TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC3607

VHF~UHF Band Low Noise Amplifier Applications

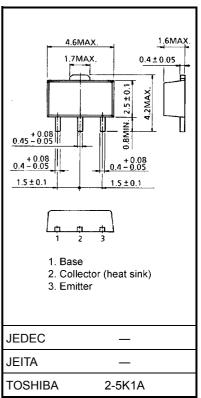
Unit: mm

- Low noise figure, high gain.
- NF = 1.1dB, $|S_{21e}|^2 = 9.5dB$ (f = 1 GHz)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	20	V
Collector-emitter voltage	V _{CEO}	12	V
Emitter-base voltage	V _{EBO}	3	V
Base current	Ι _Β	40	mA
Collector current	I _C	80	mA
		400	
Collector power dissipation	PC	800	mW
		(Note 1)	
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55~125	°C

Note 1: When mounted ceramic substrate of 250 $\text{mm}^2 \times 0.8 \text{ t}$



Weight: 0.05 g (typ.)

Microwave Characteristics (Ta = 25°C)

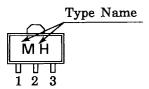
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Transition frequency	f _T	$V_{CE} = 10 \text{ V}, I_{C} = 20 \text{ mA}$	5	6.5	_	GHz
Insertion gain	S _{21e} ² (1)	$V_{CE} = 10 \text{ V}, I_C = 20 \text{ mA}, f = 500 \text{ MHz}$		15	_	- dB
	S _{21e} ² (2)	$V_{CE} = 10 \text{ V}, I_C = 20 \text{ mA}, f = 1 \text{ GHz}$	6	9.5	_	
Noise figure –	NF (1)	$V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}, f = 1 \text{ GHz}$	_	1.1	_	- dB
	NF (2)	$V_{CE} = 10 \text{ V}, I_{C} = 40 \text{ mA}, f = 1 \text{ GHz}$		1.8	3	

Electrical Characteristics (Ta = 25°C)

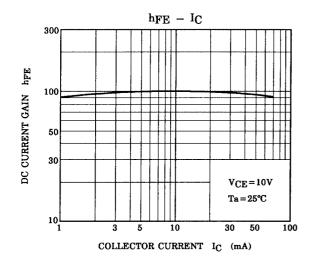
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 10 \text{ V}, I_{E} = 0$	_	_	1	μА
Emitter cut-off current	I _{EBO}	$V_{EB} = 1 \text{ V, } I_{C} = 0$	_	_	1	μА
DC current gain	h _{FE}	$V_{CE} = 10 \text{ V}, I_{C} = 20 \text{ mA}$	30	_	250	
Collecter output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz (Note 2)	_	1.15	_	pF
Reverse transfer capacitance	C _{re}		_	0.8	1.25	pF

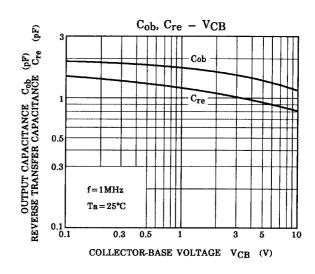
Note 2: C_{re} is measured by 3 terminal method with capacitance bridge.

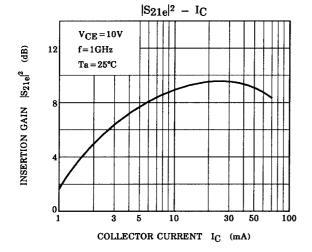
Marking

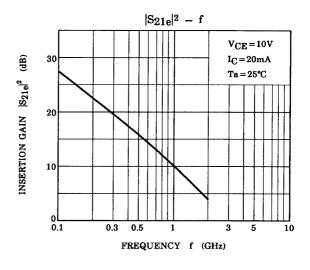


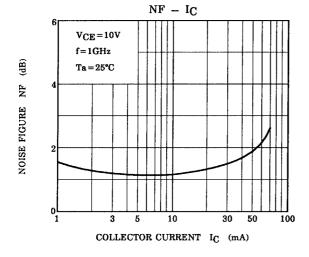
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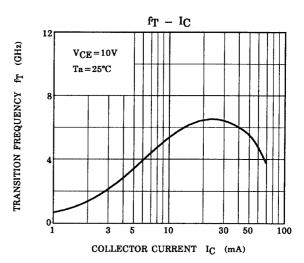




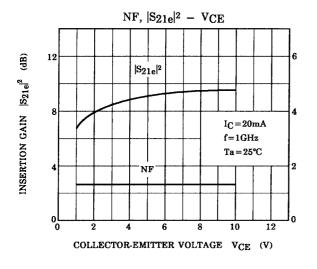


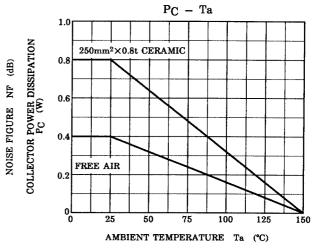






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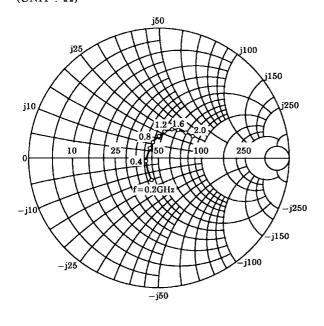


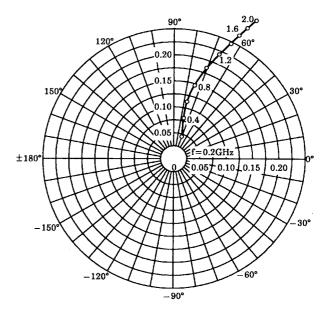
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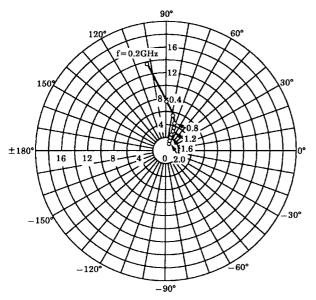
 $\begin{array}{l} S_{11e} \\ V_{CE} = 10V \\ I_{C} = 20 mA \\ Ta = 25 ^{\circ}C \\ (UNIT: \Omega) \end{array}$







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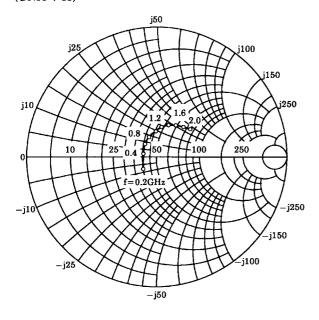


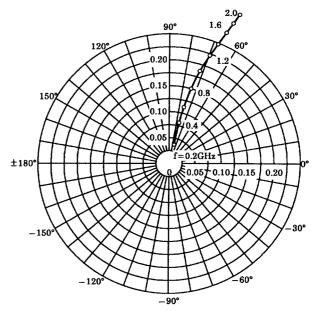
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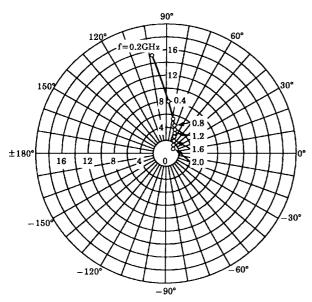
 $\begin{array}{l} S_{11e} \\ V_{CE} = 10V \\ I_{C} = 40 mA \\ Ta = 25 ^{\circ}C \\ (UNIT:\Omega) \end{array}$



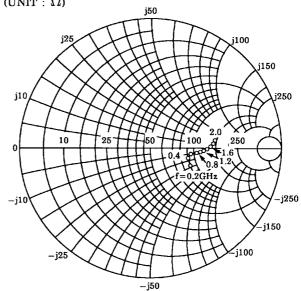




 S_{21e} $V_{CE}=10V$ $I_{C}=40mA$ $T_{a}=25^{\circ}C$



 $\begin{array}{l} S_{22e} \\ V_{CE} = 10V \\ I_{C} = 40 \mathrm{mA} \\ T_{a} = 25 ^{\circ}C \\ (UNIT:\Omega) \end{array}$



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